

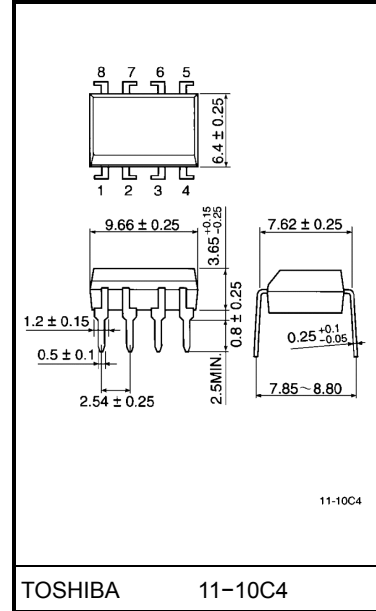
6N135, 6N136

Digital Logic Isolation.
 Line Receiver.
 Power Supply Control
 Switching Power Supply
 Transistor Inverter

The TOSHIBA 6N135 and 6N136 consists of a high emitting diode and a one chip photo diode-transistor.
 Each unit is 8-lead DIP package.

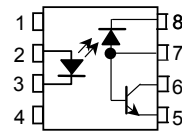
- Isolation voltage: 2500V_{rms} (min.)
- High speed: t_{pHL}, t_{pLH} = 0.5μs (typ.) (R_L = 1.9kΩ)
- TTL compatible
- If base pin is open, output signal will be noisy by environmental condition. For this base, TLP550 is suitable
- UL recognized: UL1577, file no. E67349

Unit in mm

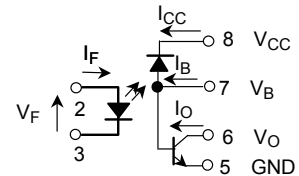


Weight: 0.54g

Pin Configurations



- 1 : N.C.
- 2 : ANODE
- 3 : CATHODE
- 4 : N.C.
- 5 : EMITTER
- 6 : COLLECTOR
- 7 : BASE, ANODE
- 8 : CATHODE



Absolute Maximum Ratings (Ta = 25°C)

| Characteristic | | Symbol | Rating | Unit |
|--|--|-----------|---------|-----------|
| LED | Forward current (Note 1) | I_F | 25 | mA |
| | Pulse forward current (Note 2) | I_{FP} | 50 | mA |
| | Total pulse forward current (Note 3) | I_{FPT} | 1 | A |
| | Reverse voltage | V_R | 5 | V |
| | Diode power dissipation (Note 4) | P_D | 45 | mW |
| Detector | Output current | I_O | 8 | mA |
| | Peak output current | I_{OP} | 16 | mA |
| | Emitter–base reverse voltage (pin 5–7) | V_{EB} | 5 | V |
| | Supply voltage | V_{CC} | –0.5~15 | V |
| | Output voltage | V_O | –0.5~15 | V |
| | Base current (pin 7) | I_B | 5 | mA |
| | Output power dissipation (Note 5) | P_O | 100 | mW |
| Operating temperature range | | T_{opr} | –55~100 | °C |
| Storage temperature range | | T_{stg} | –55~125 | °C |
| Lead solder temperature (10s) (Note 6) | | T_{sol} | 260 | °C |
| Isolation voltage (Note 7) | | BV_S | 2500 | V_{rms} |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Derate 0.8mA above 70°C.

(Note 2) 50% duty cycle, 1ms pulse width.
Derate 1.6mA / °C above 70°C.

(Note 3) Pulse width 1μs, 300pps.

(Note 4) Derate 0.9mW / °C above 70°C.

(Note 5) Derate 2mW / °C above 70°C.

(Note 6) Soldering portion of lead: Up to 2mm from the body of the device.

(Note 7) R.H. ≤ 60%, AC / 1min.

Electrical Characteristics
Over Recommended Temperature (Ta = 0°C~70°C unless otherwise noted)

| Characteristic | Symbol | Test Condition | Min. | (**)Typ. | Max. | Unit |
|--|---------------------------|---|------|-----------|------|---------------|
| Current transfer ratio | 6N135 | $I_F = 16\text{mA}, V_O = 0.4\text{V}$ $V_{CC} = 4.5\text{V}, T_a = 25^\circ\text{C}$ (Note 8) | 7 | 18 | — | % |
| | 6N136 | | 19 | 24 | — | % |
| | 6N135 | $I_F = 16\text{mA}, V_O = 0.5\text{V}$ $V_{CC} = 4.5\text{V}$ (Note 1) | 5 | 13 | — | % |
| | 6N136 | | 15 | 21 | — | % |
| Logic low output voltage | 6N135 | $I_F = 16\text{mA}, I_O = 1.1\text{mA}$ $V_{CC} = 4.5\text{V}$ | — | 0.1 | 0.4 | V |
| | 6N136 | $I_F = 16\text{mA}, I_O = 2.4\text{mA}$ $V_{CC} = 4.5\text{V}$ | — | 0.1 | 0.4 | V |
| Logic high output current | I_{OH} | $I_F = 0\text{mA}, V_O = V_{CC} = 5.5\text{V}$ $T_a = 25^\circ\text{C}$ | — | 3 | 500 | nA |
| | | $I_F = 0\text{mA}, V_O = V_{CC} = 15\text{V}$ $T_a = 25^\circ\text{C}$ | — | 0.1 | 1 | μA |
| | I_{OH} | $I_F = 0\text{mA}, V_O = V_{CC} = 15\text{V}$ | — | — | 50 | μA |
| Logic low supply current | I_{CCL} | $I_F = 16\text{mA}, V_O = \text{open}$ $V_{CC} = 15\text{V}$ | — | 40 | — | μA |
| Logic high supply current | I_{CCH} | $I_F = 0\text{mA}, V_O = \text{open}$ $V_{CC} = 15\text{V}, T_a = 25^\circ\text{C}$ | — | 0.01 | 1 | μA |
| | I_{CCH} | $I_F = 0\text{mA}, V_O = \text{open}$ $V_{CC} = 15\text{V}$ | — | — | 2 | μA |
| Input forward voltage | V_F | $I_F = 16\text{mA}, T_a = 25^\circ\text{C}$ | — | 1.65 | 1.7 | V |
| Temperature coefficient of forward voltage | $\Delta V_F / \Delta T_a$ | $I_F = 16\text{mA}$ | — | -1.9 | — | mV / °C |
| Input reverse breakdown voltage | BV_R | $I_R = 10\mu\text{A}, T_a = 25^\circ\text{C}$ | 5 | — | — | V |
| Input capacitance | C_{IN} | $f = 1\text{MHz}, V_F = 0$ | — | 60 | — | pF |
| Resistance (input-output) | R_{I-O} | $V_{I-O} = 500\text{V}$ $R.H. \leq 60\%$ (Note 9) | — | 10^{12} | — | Ω |
| Capacitance (input-output) | C_{I-O} | $f = 1\text{MHz}$ (Note 9) | — | 0.6 | — | pF |
| Transistor DC current gain | h_{FE} | $V_O = 5\text{V}, I_O = 3\text{mA}$ | — | 80 | — | — |

(**) All typicals at $T_a = 25^\circ\text{C}$

Switching Specifications

(unless otherwise specified. $T_a = 25^\circ\text{C}$, $V_{CC} = 5\text{V}$, $I_F = 16\text{mA}$)

| Characteristic | Symbol | Test Circuit | Test Condition | Min. | Typ. | Max. | Unit | |
|---|--------|--------------|-------------------|---|------|-------|------|--------------------------|
| Propagation delay time to logic low at output | 6N135 | t_{pHL} | 1 | $R_L = 4.1\text{k}\Omega$ | — | 0.2 | 1.5 | μs |
| | 6N136 | | | $R_L = 1.9\text{k}\Omega$ | — | 0.2 | 0.8 | μs |
| Propagation delay time to logic high at output | 6N135 | t_{pLH} | 1 | $R_L = 4.1\text{k}\Omega$ | — | 1.0 | 1.5 | μs |
| | 6N136 | | | $R_L = 1.9\text{k}\Omega$ | — | 0.5 | 0.8 | μs |
| Common mode transient immunity at logic high level output (Note 10) | 6N135 | CMH | 2 | $I_F = 0\text{mA}$ $V_{CM} = 10\text{V}_{p-p}$ $R_L = 4.1\text{k}\Omega$ | — | 1000 | — | $\text{V} / \mu\text{s}$ |
| | 6N136 | | | $I_F = 0\text{mA}$ $V_{CM} = 10\text{V}_{p-p}$ $R_L = 1.9\text{k}\Omega$ | — | 1000 | — | $\text{V} / \mu\text{s}$ |
| Common mode transient immunity at logic low level output (Note 10) | 6N135 | CML | 2 | $V_{CM} = 10\text{V}_{p-p}$ $R_L = 4.1\text{k}\Omega$ $I_F = 16\text{mA}$ | — | -1000 | — | $\text{V} / \mu\text{s}$ |
| | 6N136 | | | $V_{CM} = 10\text{V}_{p-p}$ $R_L = 1.9\text{k}\Omega$ $I_F = 16\text{mA}$ | — | -1000 | — | $\text{V} / \mu\text{s}$ |
| Bandwidth (Note 11) | BW | — | $R_L = 100\Omega$ | — | 2 | — | MHz | |

(Note 8) DC current transfer ratio is defined as the ratio of output collector current, I_O , to the forward LED input current, I_F , times 100%.

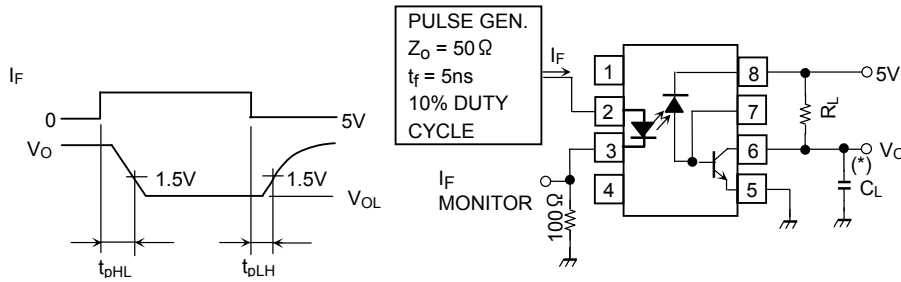
(Note 9) Device considered a two-terminal device: Pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7 and 8 shorted together.

(Note 10) Common mode transient immunity in logic high level is the maximum tolerable (positive) dv_{CM} / dt on the leading edge of the common mode pulse, V_{CM} , to assure that the output will remain in a logic high state (i.e., $V_O > 2.0\text{V}$).

Common mode transient immunity in logic low level is the maximum tolerable (negative) dv_{CM} / dt on the trailing edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a logic low state (i.e., $V_O < 0.8\text{V}$).

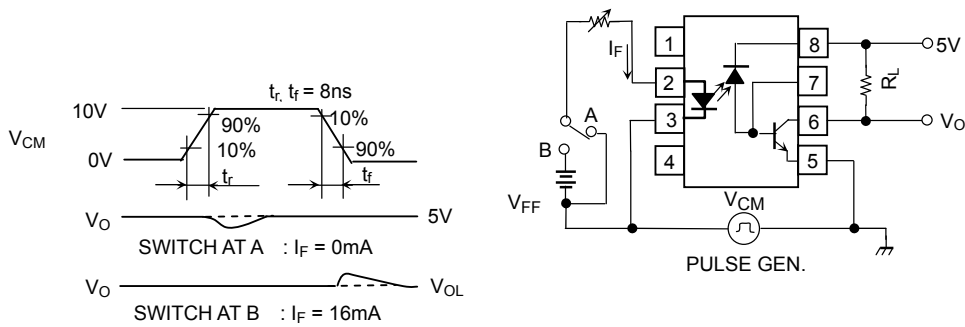
(Note 11) The frequency at which the AC output voltage is 3dB below the low frequency asymptote.

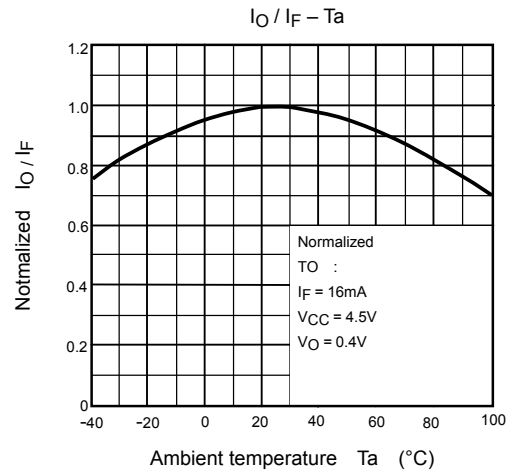
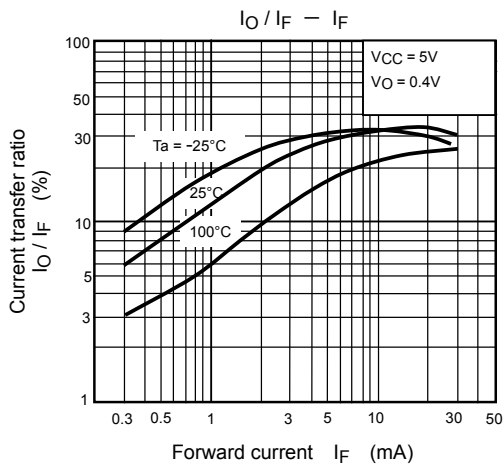
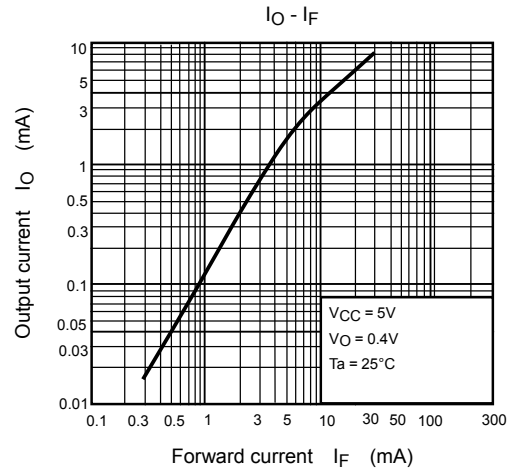
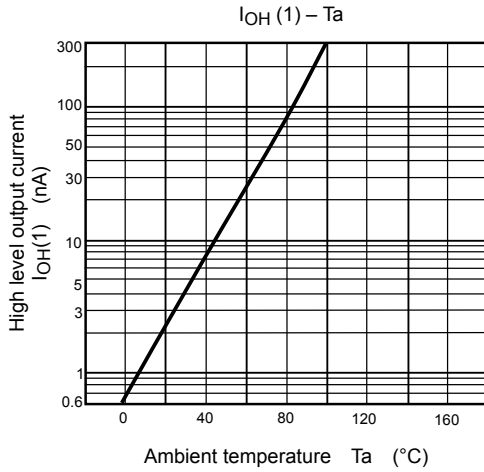
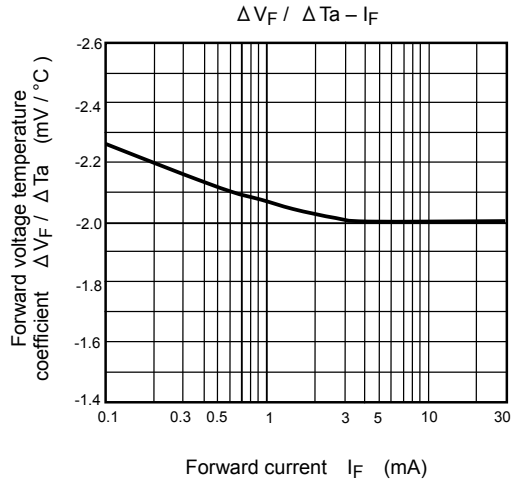
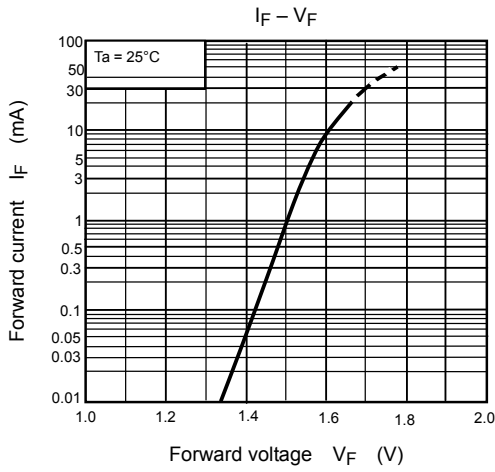
Test Circuit 1.

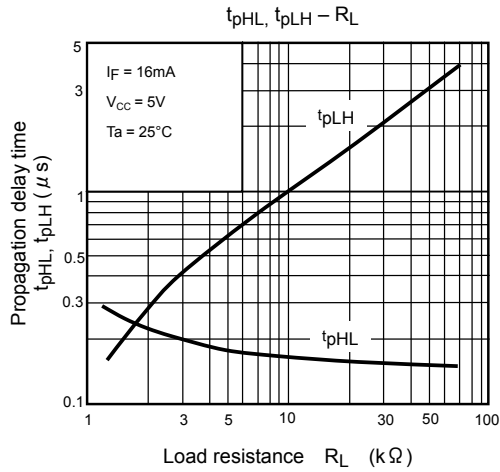
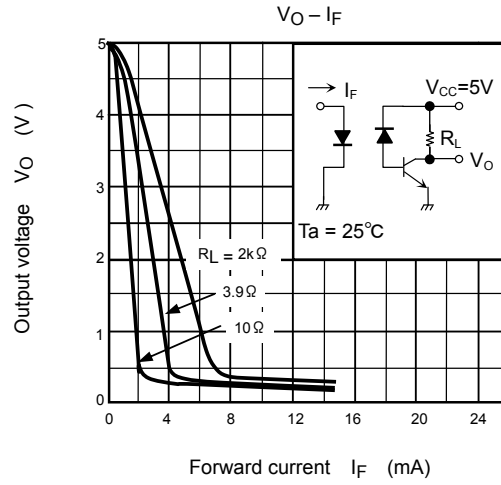
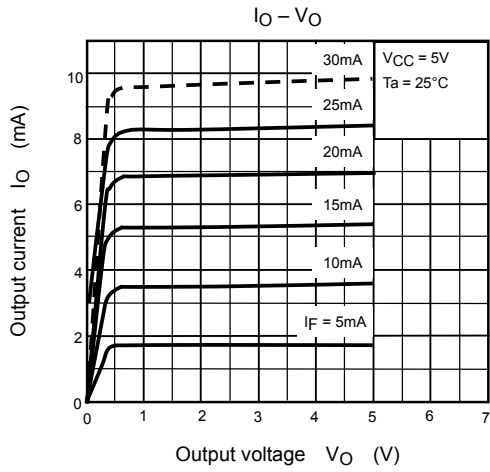


(*) C_L is approximately 15pF which includes probe and stray wiring capacitance.

Test Circuit 2.







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20070701-EN

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